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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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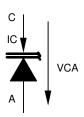
DS9502 ESD Protection Diode

www.dalsemi.com

SPECIAL FEATURES

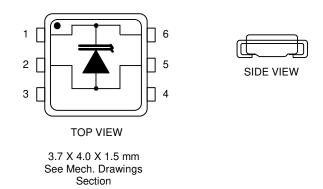
- Zener characteristic with voltage snap-back to protect against ESD hits
- High avalanche voltage, low leakage and low capacitance avoid signal attenuation
- Compatible to all 5V logic families
- Space saving, low inductance TSOC surface mount package
- Symmetric dual–port bondout to maximize energy dissipation in protection device
- Industrial temperature range

SYMBOL AND CONVENTIONS



PACKAGE OUTLINE

TSOC SURFACE MOUNT PACKAGE



ORDERING INFORMATION

DS9502P 6-lead TSOC package

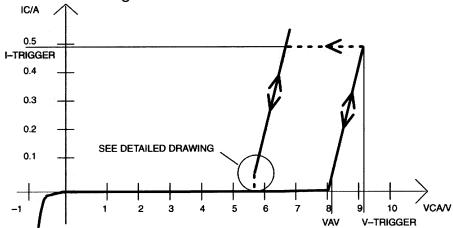
DESCRIPTION

This DS9502 was designed as an additional ESD protection for SRAM-based battery-buffered portable memory modules. The memory chips used for these modules have already a strong ESD-protection structure on their I/O line. Together with the DS9502 the ESD protection level is raised to more than 27 kV (IEC 801–2 Reference model). In case of abnormal ESD hits beyond its maximum ratings the DS9502 will eventually fail "short" thus preventing further damage.

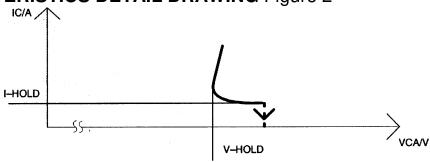
During normal operation the DS9502 behaves like a regular 7.5V Zener Diode. When the voltage exceeds the trigger voltage, the I/V characteristic of the device will "snapback" allowing the same or higher amount of current to flow, but at a significantly lower voltage. As long as a minimum current or voltage is maintained, the device will stay in the "snapback mode". If the voltage or the current falls below the holding voltage or holding current, the device will abruptly change to its normal mode and conduct only a small leakage current.

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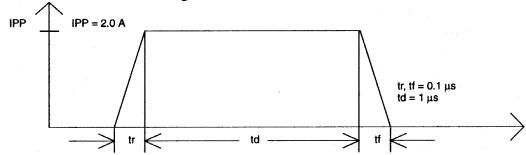
DC CHARACTERISTICS Figure 1



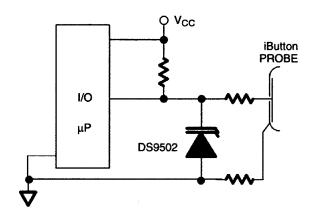
DC CHARACTERISTICS DETAIL DRAWING Figure 2



TEST PULSE WAVEFORM Figure 3



TYPICAL APPLICATION Figure 4



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PHYSICAL SPECIFICATIONS

Size See mechanical drawing

Weight 0.5 grams

ABSOLUTE MAXIMUM RATINGS*

Operating Temperature -40°C to $+85^{\circ}\text{C}$ Storage Temperature -55°C to $+125^{\circ}\text{C}$ Soldering Temperature 260°C for 10 seconds

Continuous DC Current Through Package 80 mA

ELECTRICAL CHARACTERISTICS

 $(-40^{\circ}C \text{ to } +85^{\circ}C)$

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Leakage Current	I_L		30	100	nA	2
Avalanche Voltage	V_{AV}	7.4		7.8	V	1,3
Trigger Voltage	V _{TRIGGER}		9.0	9.5	V	1
Trigger Current	I _{TRIGGER}		600	1000	mA	
Holding Voltage	V_{HOLD}	5.5			V	1
Holding Current	I _{HOLD}	30			mA	
Forward Voltage (-10 mA)	V_{F}		-0.7	-0.8	V	4
Forward Current (-0.7V)	I_{F}		-10	-100	mA	4
Maximum Peak Current	I_{PP}		2.0		A	5
Continuous Current Through Diode	I_{CC}			±160	mA	6

CAPACITANCE $(t_A=25^{\circ}C)$

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Junction Capacitance (5V)	C_{J5}		55		pF	1
Junction Capacitance (0V)	C_{J0}		100		pF	1

THERMAL RESISTANCE

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Junction To Package	$R_{\Theta JC}$			75	K/W	
Junction To Ambient	$R_{\Theta JA}$			200	K/W	

NOTES:

- 1. All voltages are referenced from Cathode to Anode.
- 2. At 7.0V.
- 3. At $0.3 \,\mu A$.
- 4. Typical values at room temperature.
- 5. See pulse specification.
- 6. In either direction (forward or reverse) through the diode (pins 1 & 6 and 2 & 5 tied together, otherwise +80 mA max).

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^{*} This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.